## **Dual Non-Inverting Schmitt-Trigger Buffer**

The NLU2G17 MiniGate<sup>™</sup> is an advanced high–speed CMOS dual non–inverting Schmitt–trigger buffer in ultra–small footprint.

The NLU2G17 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

The NLU2G17 can be used to enhance noise immunity or to square up slowly changing waveforms.

### **Features**

- High Speed:  $t_{PD} = 4.0 \text{ ns (Typ)} @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1 \mu A \text{ (Max)}$  at  $T_A = 25^{\circ}\text{C}$
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb–Free Devices

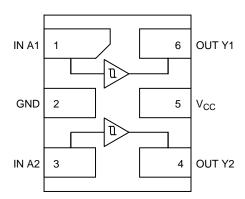


Figure 1. Pinout (Top View)

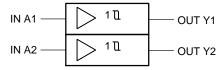


Figure 2. Logic Symbol

### **PIN ASSIGNMENT**

1	IN A1
2	GND
3	IN A2
4	OUT Y2
5	V <sub>CC</sub>
6	OUT Y1

# FUNCTION TABLE A Y L L H H



### ON Semiconductor®

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### MARKING DIAGRAMS



UDFN6 1.0 x 1.0 CASE 517BX





UDFN6 1.2 x 1.0 CASE 517AA





UDFN6 1.45 x 1.0 CASE 517AQ





ULLGA6 1.45 x 1.0 CASE 613AF



Μ

= Date Code

### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 4 of this data sheet.

### **MAXIMUM RATINGS**

Symbol	Paramet	ter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
l <sub>ok</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	±20	mA
Ι <sub>Ο</sub>	DC Output Source/Sink Current		±12.5	mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin	±25	mA	
I <sub>GND</sub>	DC Ground Current per Ground Pin	±25	mA	
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C	
TL	T <sub>L</sub> Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
$T_J$	T <sub>J</sub> Junction Temperature Under Bias		150	°C
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating Oxygen	Index: 28 to 34	UL 94 V-0 @ 0.125 in	
I <sub>LATCHUP</sub>	Latchup Performance Above V <sub>CC</sub> and Below	±500	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

2. Tested to EIA / JESD78.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	1.65	5.5	V
V <sub>IN</sub>	Digital Input Voltage	0	5.5	V
V <sub>OUT</sub>	Output Voltage	0	5.5	V
T <sub>A</sub>	Operating Free–Air Temperature		+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate $ \begin{array}{c} V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V} \\ V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V} \end{array} $	0	No Limit No Limit	ns/V

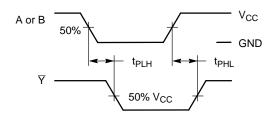
### DC ELECTRICAL CHARACTERISTICS

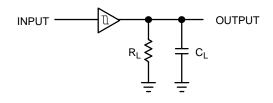
			V <sub>CC</sub>	T <sub>A</sub> = 25 °C		T <sub>A</sub> = 25 °C		T <sub>A</sub> = -	⊦85°C		55°C to 5°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit	
V <sub>T+</sub>	Positive Threshold Voltage		3.0 4.5 5.5		2.0 3.0 3.6	2.2 3.15 3.85		2.2 3.15 3.85		2.2 3.15 3.85	V	
V <sub>T-</sub>	Negative Threshold Voltage		3.0 4.5 5.5	0.9 1.35 1.65	1.5 2.3 2.9	1.65 2.46 3.05	0.9 1.35 1.65		0.9 1.35 1.65		V	
V <sub>H</sub>	Hysteresis Voltage		3.0 4.5 5.5	0.30 0.40 0.50	0.57 0.67 0.74	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	V	
V <sub>OH</sub>	Minimum High-Level Output	$V_{IN} \ge V_{T+MAX}$ $I_{OH} = -50 \mu\text{A}$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		1.9 2.9 4.4		V	
	Voltage	$V_{IN} \ge V_{T+MAX}$ $I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$	3.0 4.5	2.58 3.94			2.48 3.80		2.34 3.66			
V <sub>OL</sub>	Maximum Low-Level Output Voltage	$V_{IN} \le V_{T-MIN}$ $I_{OL} = 50 \mu A$	2.0 3.0 4.5		0 0 0	0.1 0.1 0.1		0.1 0.1 0.1		0.1 0.1 0.1	V	
	voltage	$V_{IN} \le V_{T-MIN}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$	3.0 4.5			0.36 0.36		0.44 0.44		0.52 0.52		
I <sub>IN</sub>	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	0 to 5.5			±0.1		±1.0		±1.0	μΑ	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = 5.5 V or GND	5.5			1.0		10		40	μΑ	

### AC ELECTRICAL CHARACTERISTICS (Input $t_f = t_f = 3.0 \text{ ns}$ )

		V <sub>CC</sub>	Test		T <sub>A</sub> = 25 °	С	T <sub>A</sub> =	+85°C	T <sub>A</sub> = -5 +12	55°C to 5°C	
Symbol	Parameter	(V)	Condition	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay,	3.0 to	C <sub>L</sub> = 15 pF		7.0	12.8	1.0	15	1.0	17	ns
t <sub>PHL</sub>	Input Ā to Output ₹	3.6	C <sub>L</sub> = 50 pF		8.5	16.3	1.0	18.5	1.0	20.5	i
		4.5 to	C <sub>L</sub> = 15 pF		4.0	8.6	1.0	10	1.0	11.5	
		5.5	C <sub>L</sub> = 50 pF		5.5	10.6	1.0	12	1.0	13.5	
C <sub>IN</sub>	Input Capacitance				5.0	10		10		10	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 3)	5.0			7.0						pF

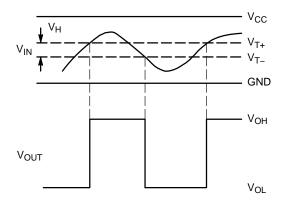
<sup>3.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation  $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no–load dynamic power consumption:  $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC}$ .



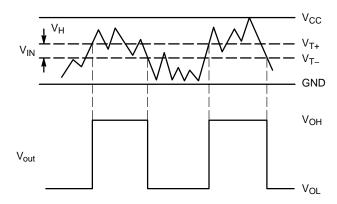


A 1-MHz square input wave is recommended for propagation delay tests.

Figure 3. Switching Waveforms







(a) A Schmitt-Trigger Squares Up Inputs With Slow Rise and Fall Times

(b) A Schmitt-Trigger Offers Maximum Noise Immunity

Figure 5. Typical Schmitt-Trigger Applications

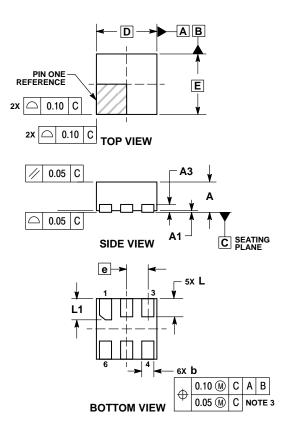
### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLU2G17MUTCG	UDFN6, 1.2 x 1.0, 0.4P (Pb-Free)	3000 / Tape & Reel
NLU2G17AMUTCG	UDFN6, 1.45 x 1.0, 0.5P (Pb-Free)	3000 / Tape & Reel
NLU2G17CMUTCG	UDFN6, 1.0 x 1.0, 0.35P (Pb-Free)	3000 / Tape & Reel
NLU2G17AMX1TCG	ULLGA6, 1.45 x 1.0, 0.5P (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **PACKAGE DIMENSIONS**

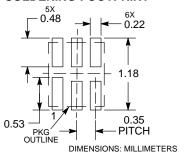
UDFN6 1.0x1.0, 0.35P CASE 517BX ISSUE O



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION: MILLIMETERS.
   DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
   PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

DIM	MILLIN MIN 0.45	ETERS MAX			
-					
	0.45				
Α		0.55			
A1	0.00	0.05			
A3	0.13 REF				
b	0.12	0.22			
D	1.00 BSC				
E	1.00 BSC				
е	0.35	BSC			
L	0.25	0.35			
L1	0.30	0.40			

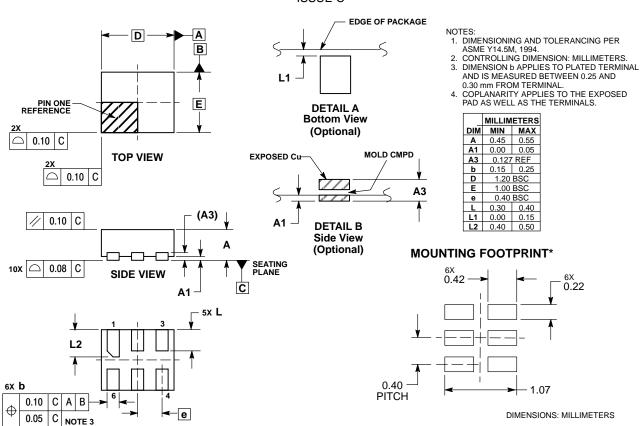
### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **PACKAGE DIMENSIONS**

### UDFN6, 1.2x1.0, 0.4P CASE 517AA ISSUE C

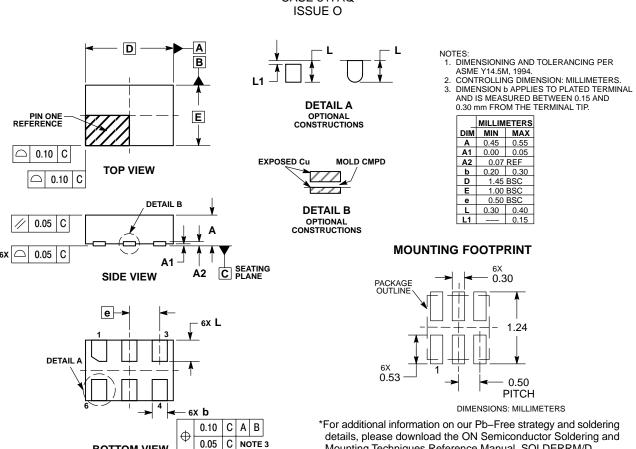


**BOTTOM VIEW** 

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **PACKAGE DIMENSIONS**

### UDFN6 1.45x1.0, 0.5P CASE 517AQ

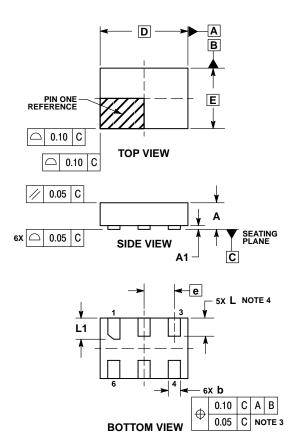


Mounting Techniques Reference Manual, SOLDERRM/D.

**BOTTOM VIEW** 

### PACKAGE DIMENSIONS

### ULLGA6 1.45x1.0, 0.5P CASE 613AF ISSUE A



#### NOTES:

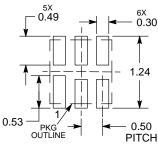
- 1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.

  CONTROLLING DIMENSION: MILLIMETERS.
- 3. DIMENSION 5 APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.

  4. A MAXIMUM OF 0.05 PULL BACK OF THE
- A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED.

$\overline{}$				
	MILLIMETERS			
DIM	MIN	MAX		
Α	-	0.40		
A1	0.00	0.05		
b	0.15	0.25		
D	1.45 BSC			
E	1.00 BSC			
е	0.50 BSC			
L	0.25	0.35		
L1	0.30	0.40		

### MOUNTING FOOTPRINT SOLDERMASK DEFINED\*



DIMENSIONS: MILLIMETERS

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